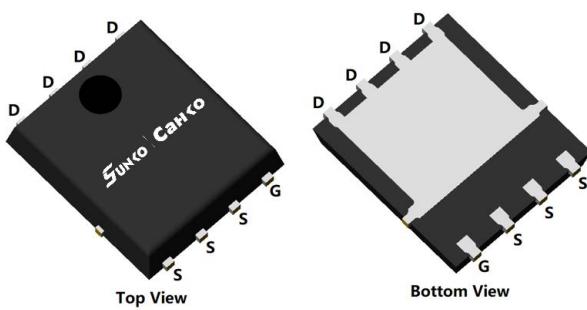
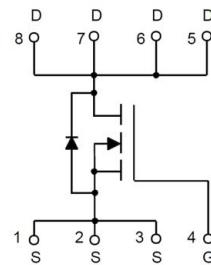


P-Channel Enhancement Mode Field Effect Transistor



PDFN5060-8L



Product Summary

- V_{DS} -40 V
- I_D -60 A
- $R_{DS(on)}$ (at $V_{GS}=-10V$) $<7.5\text{ m}\Omega$
- $R_{DS(on)}$ (at $V_{GS}=-4.5V$) $<10.5\text{ m}\Omega$
- 100% EAS Tested
- 100% ∇V_{DS} Tested

General Description

- Trench Power MOSFET technology
- Low $R_{DS(on)}$ & FOM
- Excellent stability and uniformity
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- Power management
- Portable equipment

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-source Voltage	V_{DS}	-40	V
Gate-source Voltage	V_{GS}	± 25	V
Drain Current	I_D	-14	A
		-9	
		-60	
		-38	
Pulsed Drain Current ^A	I_{DM}	-240	A
Avalanche energy ^B	EAS	400	mJ
Total Power Dissipation ^C	P_D	2.5	W
		1	
		83	
		33	
Junction and Storage Temperature Range	T_J, T_{STG}	-55~+150	°C

Thermal resistance

Parameter	Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient ^D	$R_{\theta JA}$	40	50	°C/W
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	1.2	1.5	

Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
SCG60P04A	F1	SCG60P04A	5000	10000	100000	13" reel

■ Electrical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=-250\mu\text{A}$	-40	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=-40\text{V}, V_{\text{GS}}=0\text{V}$	-	-	-1	μA
		$V_{\text{DS}}=-40\text{V}, V_{\text{GS}}=0\text{V}, T_J=150^\circ\text{C}$	-	-	-100	
Gate-Body Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 25\text{V}, V_{\text{DS}}=0\text{V}$	-	-	± 100	nA
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=-250\mu\text{A}$	-1.2	-1.7	-2.5	V
Static Drain-Source On-Resistance	$R_{\text{DS(on)}}$	$V_{\text{GS}}=-10\text{V}, I_{\text{D}}=-30\text{A}$	-	5.5	7.5	$\text{m}\Omega$
		$V_{\text{GS}}=-10\text{V}, I_{\text{D}}=-20\text{A}$	-	5.5	7.5	
		$V_{\text{GS}}=-4.5\text{V}, I_{\text{D}}=-20\text{A}$	-	7.5	10.5	
Diode Forward Voltage	V_{SD}	$I_{\text{S}}=-30\text{A}, V_{\text{GS}}=0\text{V}$	-	-0.85	-1.2	V
Gate resistance	R_{G}	$f=1\text{MHz}$	-	15	-	Ω
Maximum Body-Diode Continuous Current	I_{S}		-	-	-60	A
Dynamic Parameters						
Input Capacitance	C_{iss}	$V_{\text{DS}}=-20\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$	-	4600	-	pF
Output Capacitance	C_{oss}		-	490	-	
Reverse Transfer Capacitance	C_{rss}		-	470	-	
Switching Parameters						
Total Gate Charge	Q_{g}	$V_{\text{GS}}=-10\text{V}, V_{\text{DS}}=-20\text{V}, I_{\text{D}}=-30\text{A}$	-	99	-	nC
Gate-Source Charge	Q_{gs}		-	14	-	
Gate-Drain Charge	Q_{gd}		-	22	-	
Reverse Recovery Charge	Q_{rr}	$I_{\text{F}}=-30\text{A}, \text{di}/\text{dt}=100\text{A}/\text{us}$	-	16	-	nC
Reverse Recovery Time	t_{rr}		-	16	-	
Turn-on Delay Time	$t_{\text{D(on)}}$	$V_{\text{GS}}=-10\text{V}, V_{\text{DD}}=-20\text{V}, I_{\text{D}}=-30\text{A}$ $R_{\text{GEN}}=3\Omega$	-	11	-	ns
Turn-on Rise Time	t_{r}		-	52	-	
Turn-off Delay Time	$t_{\text{D(off)}}$		-	331	-	
Turn-off fall Time	t_{f}		-	185	-	

A. Repetitive rating; pulse width limited by max. junction temperature.

B. $T_J=25^\circ\text{C}, V_{\text{DD}}=-30\text{V}, V_{\text{G}}=-10\text{V}, R_{\text{G}}=25\Omega, L=2\text{mH}, I_{\text{AS}}=-20\text{A}$.C. P_d is based on max. junction temperature, using junction-case and junction-ambient thermal resistance.D. The value of $R_{\theta JA}$ is measured with the device mounted on the minimum recommend pad size, in the still air environment with $TA = 25^\circ\text{C}$. The maximum allowed junction temperature of 150°C . The value in any given application depends on the user's specific board design.

■ Typical Electrical and Thermal Characteristics Diagrams

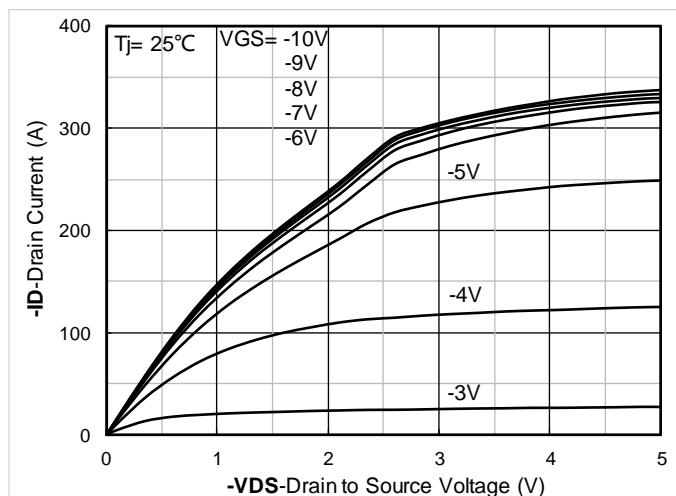


Figure 1. Output Characteristics

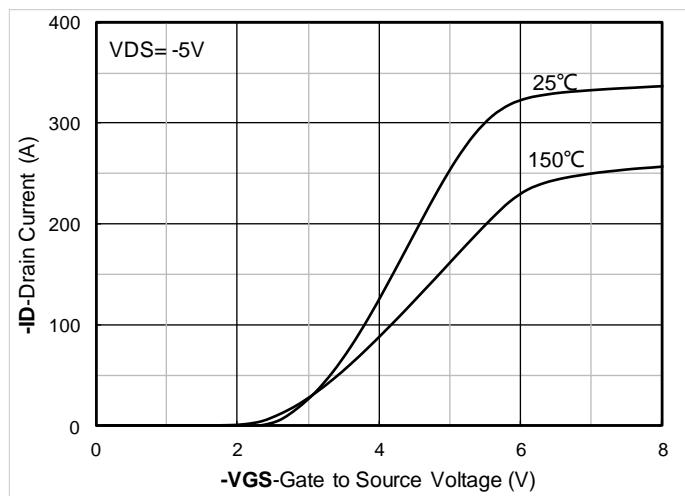


Figure 2. Transfer Characteristics

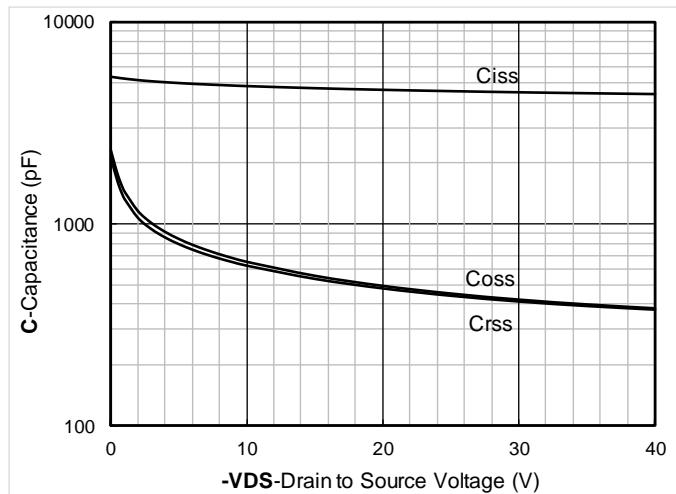


Figure 3. Capacitance Characteristics

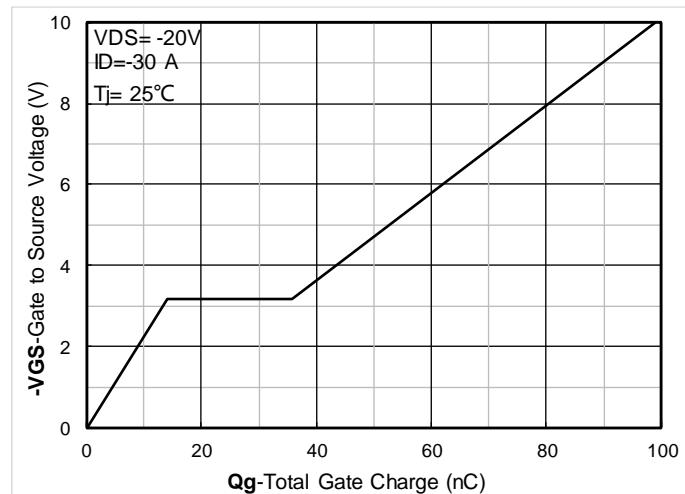


Figure 4. Gate Charge

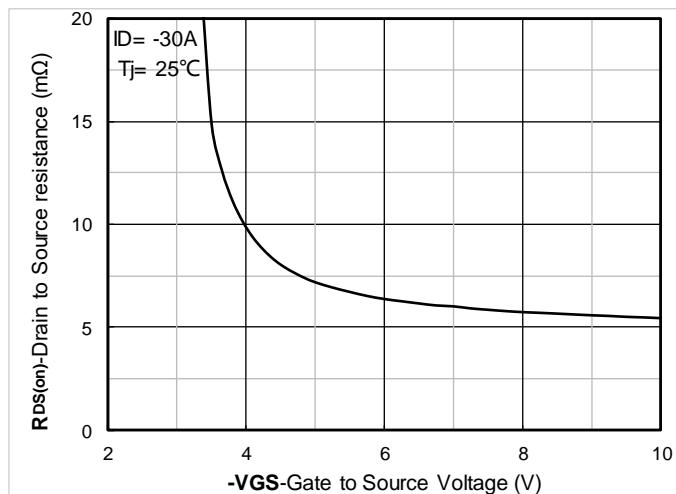


Figure 5. On-Resistance vs Gate to Source Voltage

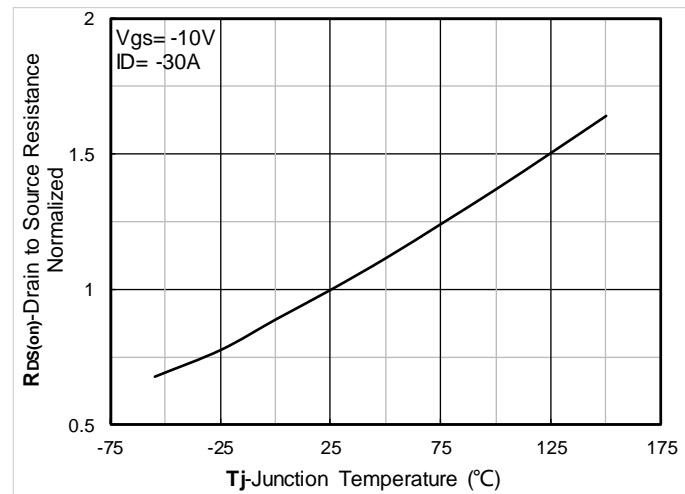


Figure 6. Normalized On-Resistance

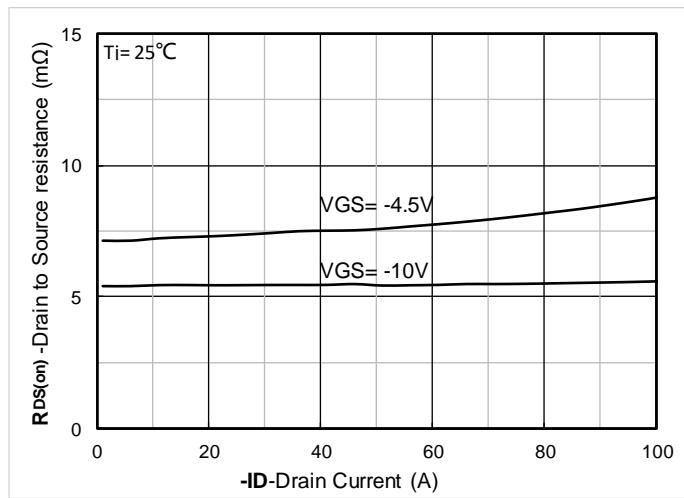


Figure 7. RDS(on) VS Drain Current

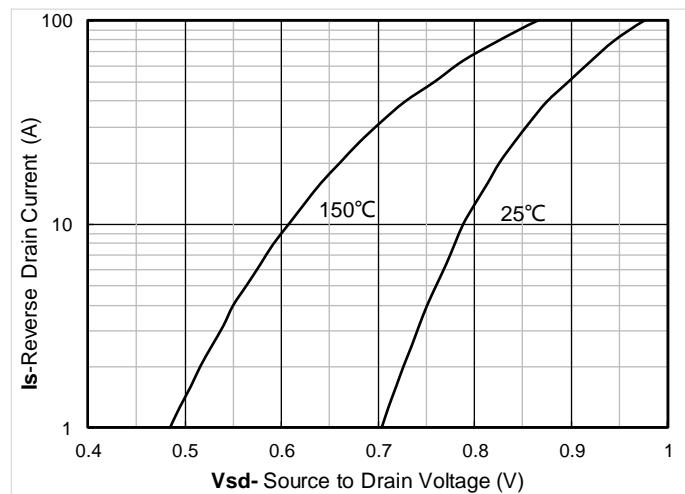


Figure 8. Forward characteristics of reverse diode

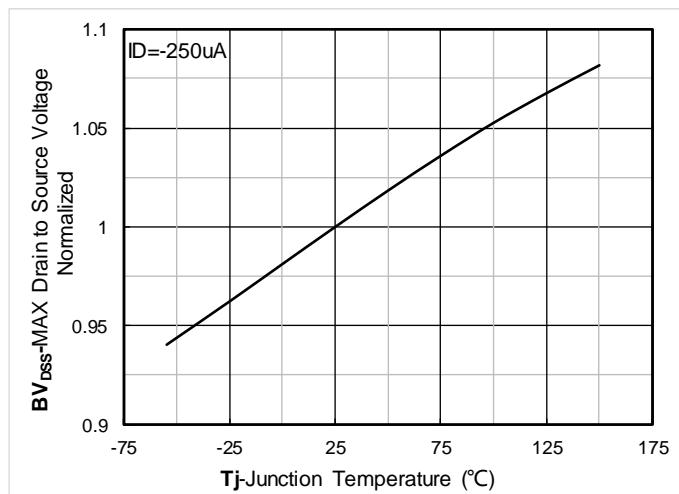


Figure 9. Normalized breakdown voltage

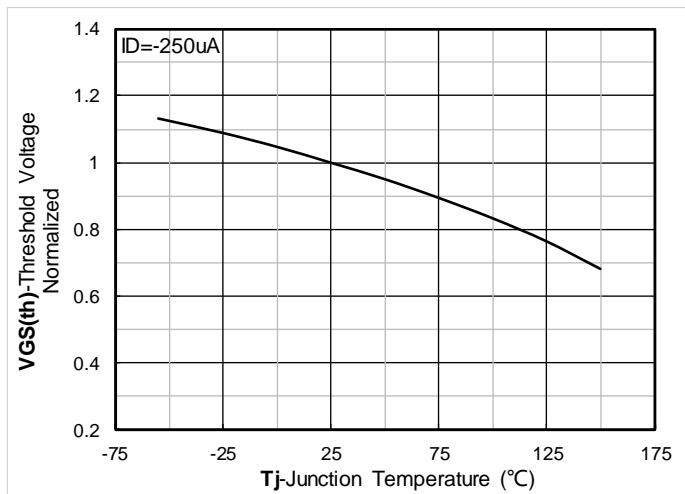


Figure 10. Normalized Threshold voltage

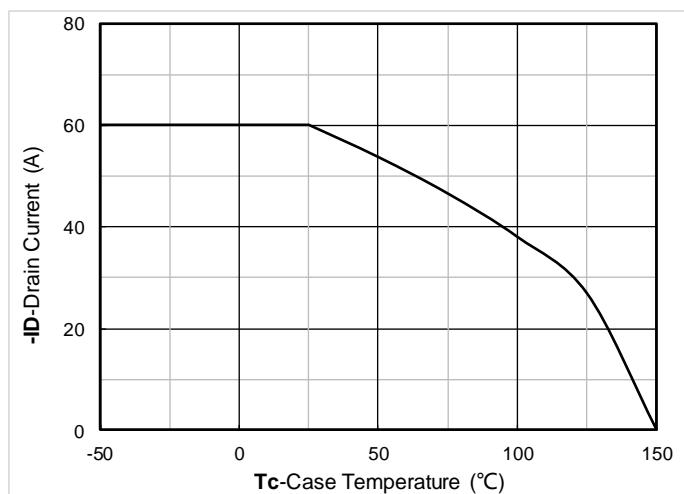


Figure 11. Current dissipation

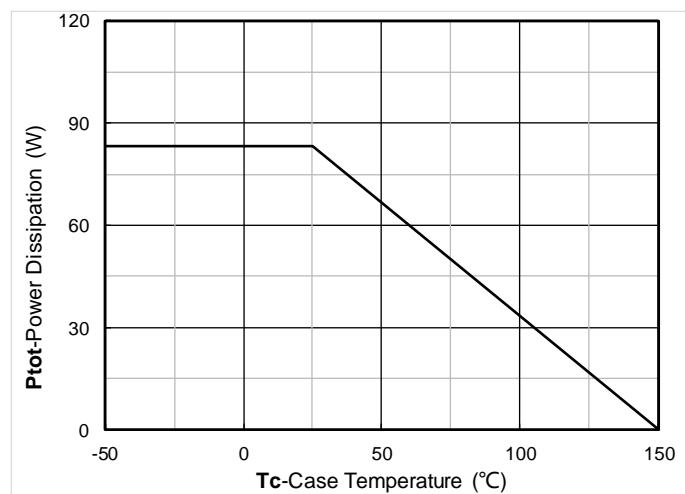


Figure 12. Power dissipation

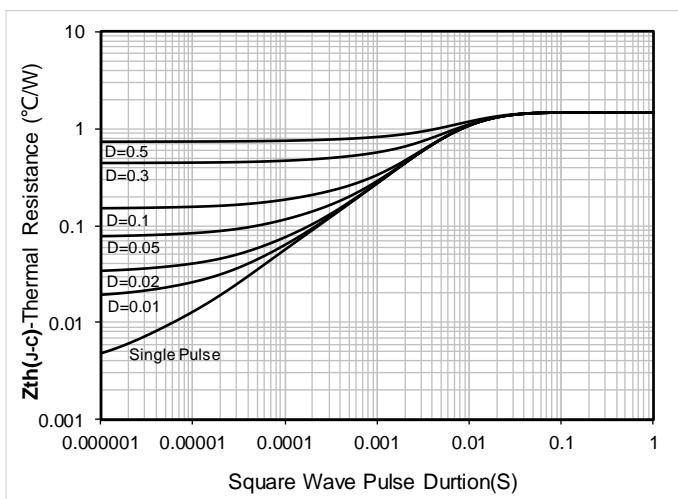


Figure 13. Maximum Transient Thermal Impedance

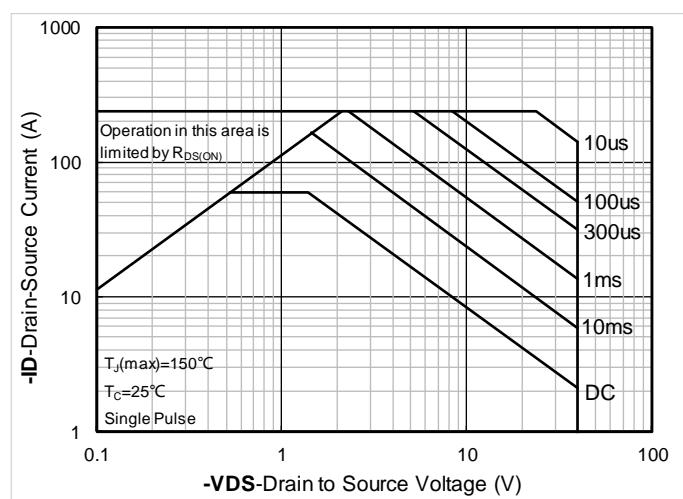
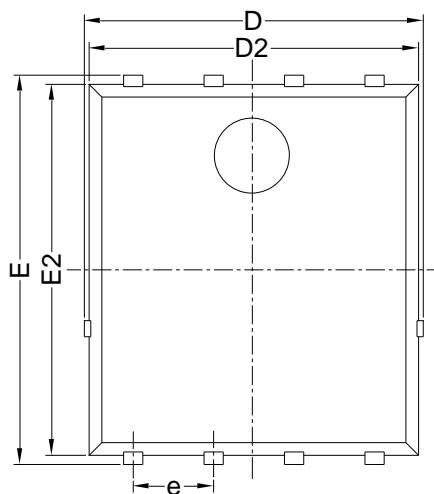
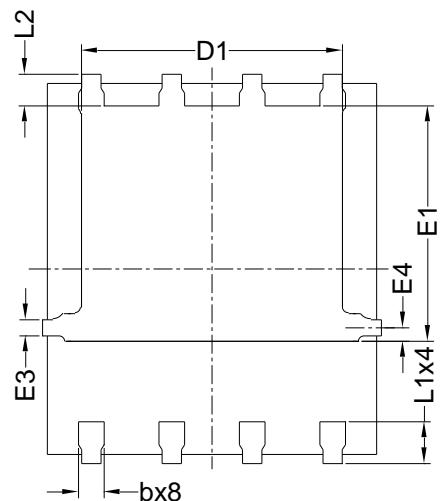


Figure 14. Safe Operation Area

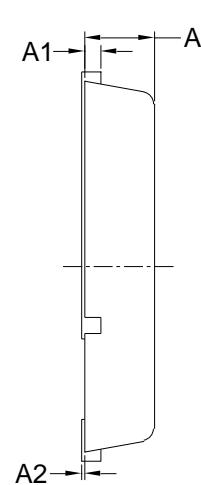
■ PDFN5060-8L-B-1.1MM Package information



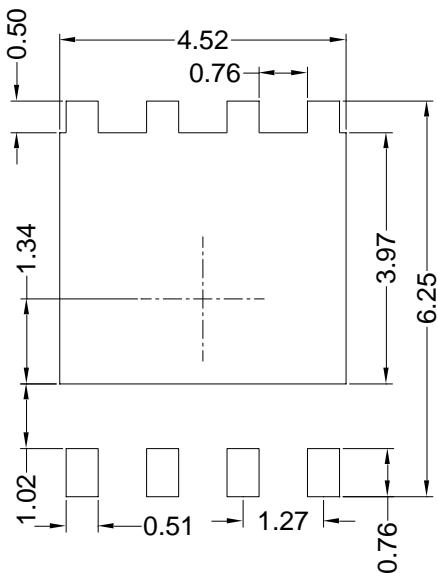
Top View
正面视图



Bottom View
背面视图



Side View
侧面视图



Suggested Solder Pad Layout
Top View

SYMBOL	MILLIMETER		
	MIN	NOM	MAX
D	5.15	5.35	5.55
E	5.95	6.15	6.35
A	1.00	1.10	1.20
A1	0.254 BSC		
A2			0.10
D1	3.92	4.12	4.32
E1	3.52	3.72	3.92
D2	5.00	5.20	5.40
E2	5.66	5.86	6.06
E3	0.254 REF		
E4	0.21 REF		
L1	0.56	0.66	0.76
L2	0.50 BSC		
b	0.31	0.41	0.51
e	1.27 BSC		

Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.10\text{mm}$.
3. The pad layout is for reference purposes only.

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